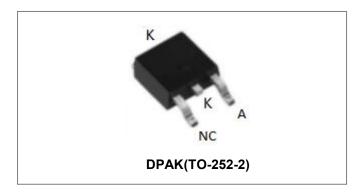






S3D10065E1 650V SIC POWER SCHOTTKY RECTIFIER



Description

S3D10065E1 is a SiC Schottky rectifier packaged in DPAK(TO-252-2) case. The device is high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D10065E1 is ideal for energy sensitive, high frequency applications in challenging environments.

Circuit Diagram



Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

Features

- 175°C T_J operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request







Maximum Ratings

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	-	650	>
	I _{F (AV)1}	Tc=25°C	31	Α
Average Rectified Forward Current	I _{F (AV)2}	Tc=135°C	14	Α
	I _{F (AV)3}	Tc=150°C	10	Α
Repetitive Peak Forward Surge Current	I _{FRM1}	10ms, Half Sine pulse, Tc =25°C	55	Α
	I _{FRM2}	10ms, Half Sine pulse, Tc=110°C	40	Α
	I _{FSM1}	10ms, Half Sine pulse, Tc =25°C	115	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM2}	10ms, Half Sine pulse, Tc =110°C	80	Α
Non-Repetitive Peak Forward Surge Current	I _{F,Max1}	10µs. Pulse, Tc=25℃	995	Α
	I _{F,Max2}	10µs. Pulse, Tc=110℃	685	Α
D 0: : ::	P _{tot1}	Tc =25°C	100	W
Power Dissipation	P _{tot2}	Tc=110°C	43	W

Electrical Characteristics:

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V_{F1}	@ 10A, Pulse, T _J = 25 °C	1.45	1.7	V
l comment of the graph of the g	V_{F2}	@ 10A, Pulse, T _J = 175 °C	1.65	2.0	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}C$	0.7	40	uA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 175 ^{\circ}\text{C}$	7	160	uA
Junction Capacitance	Ст	V _R =0V, T _J =25℃, f=1MHz	680	-	pF
Reverse Recovery Charge	Qc	I _F = 10A, di/dt = 200A/μs VR = 400 V, T _J =25°C	42.4	-	nC
Capacitance Stored Energy	Ec	V _R = 400 V, T _J =25°C	10.4	-	μЈ

 $^{^*}$ Pulse width < 300 μ s, duty cycle < 2%



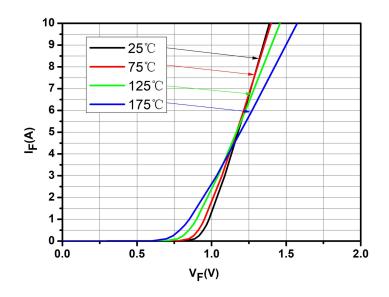




Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	T_J	-	-55 to +175	°C
Storage Temperature	T _{stg}	-	-55 to +175	°C
Maximum Thermal Resistance Junction to Case	$R_{ t qJC}$	DC operation	1.5	°C/W

Ratings and Characteristics Curves



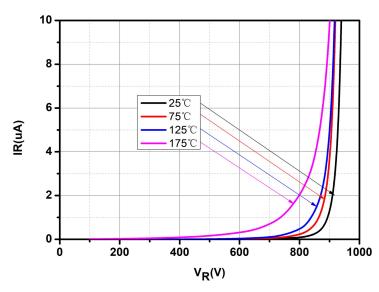


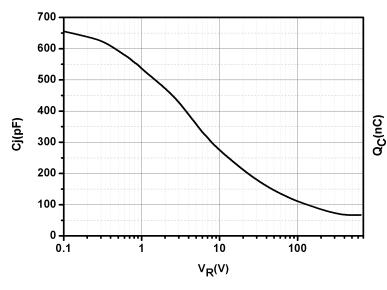
Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics









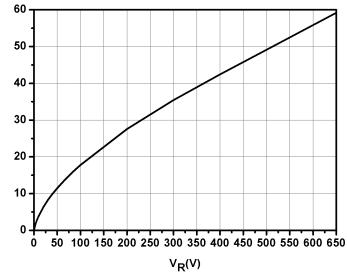
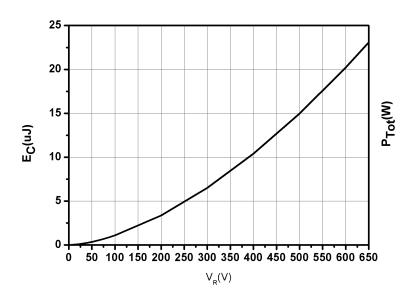


Fig.3-Capacitance vs. Reverse Voltage

Fig.4-Total Capacitance Charge vs. Reverse Voltage



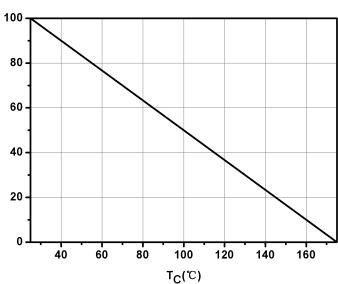


Fig.5-Capacitance Stored Energy

Fig.6-Power Derating

[•] China - Germany - Korea - Singapore - United States •

[•] http://www.smc-diodes.com - sales@ smc-diodes.com •







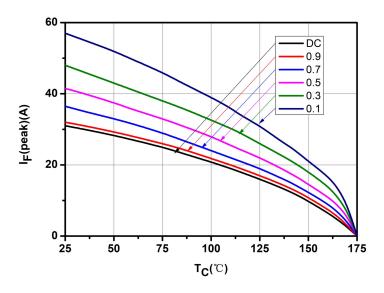


Fig.7-Current Derating

Ordering Information

Device	Package	Shipping
S3D10065E1	DPAK (TO-252-2)	2500pcs / reel
S3D10065E1TR	DPAK (TO-252-2)	2500pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

Marking Diagram



Where XXXXX is YYWWL

 S3D
 = Device Type

 E1
 = Package type

 10
 = Forward Current (10A)

 065
 = Reverse Voltage (650V)

 SSG
 = SSG

 YY
 = Year

 WW
 = Week

 L
 = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

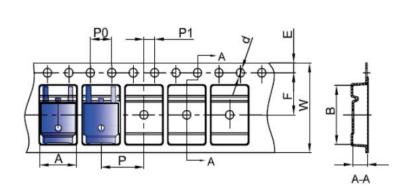
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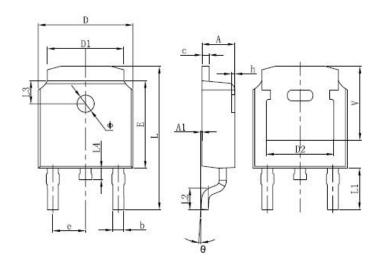


Carrier Tape & Reel Specification DPAK(TO-252-2)



SYMBOL	Millimeters		
STWIBOL	Min.	Max.	
Α	6.80	7.00	
В	10.40	10.60	
С	2.60	2.80	
d	Ф1.45	Ф1.65	
Е	1.65	1.85	
F	7.40	7.60	
P0	3.90	4.10	
Р	7.90	8.10	
P1	1.90	2.10	
W	15.90	16.30	

Mechanical Dimensions DPAK(TO-252-2)



SYMBOL	Dimensions in millimeters			
	Min.	Тур.	Max.	
Α	2.18	-	2.39	
A1	_	-	0.13	
b	0.64	_	0.89	
С	0.46	-	0.89	
D	6.35	-	6.73	
D1	4.95	_	5.46	
D2	4.32	-	-	
E	5.97	6.1	6.22	
е	2.29BSC			
L	9.4	_	10.41	
L1	2.90 REF.			
L2	1.4	1.52	1.78	
L3	1.60 REF.			
L4	-	-	1.02	
Ф	1.1	_	1.3	
Θ	0°	-	10°	
V	5.21	-	-	

- China Germany Korea Singapore United States
 - http://www.smc-diodes.com sales@ smc-diodes.com •







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